

In the Abstract:

Please replace the Abstract of the Disclosure with the new Abstract of the Disclosure, attached hereto as a separate sheet.

Remarks:

This preliminary amendment is being submitted in an effort to correct informalities and provide improved translations of certain wording in the initial application, and to present claims in proper U.S. claims idiom. The changes are not made for any reason related to the statutory requirements for a patent nor do they narrow the scope of the claim for any reason related to the statutory requirements for a patent. The newly entered claims are fully supported in the original claims.

The recommended subheadings have been inserted at the proper locations in the text.

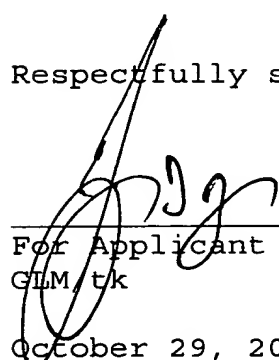
New FIGS. 1 and 2 of the drawings are submitted for approval. Specifically, the figures have been given separate labels.

All of the changes are properly supported in the original application. No new matter has been added.

An early action on the merits of the application is solicited.

Please charge any fees that might be due with respect to
Sections 1.16 and 1.17 to the Deposit Account of Lerner and
Greenberg, P.A., No. 12-1099.

Respectfully submitted,

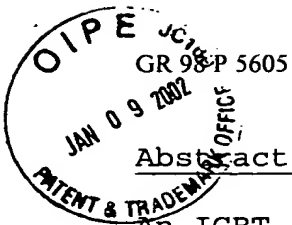


For Applicant
GLM/tk

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Abstract of the Disclosure:

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5 An IGBT structure includes successive regions whose conductivities have alternating signs. The structure is dimensioned for punch-through and is provided with two buffer layers. As a result, the component becomes symmetrically blocking and is suitable as a semiconductor switch, e.g., for converters.

GLM